

BFP840ESD

**Low Noise Amplifier for 5 to 6 GHz
WLAN Application using BFP840ESD
with 2.4 GHz Rejection**

Application Note AN317

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1 Introduction

1.1 Wi-Fi®

Wireless Fidelity (Wi-Fi®) plays a major role in today's communications by enabling constant connection in the 2.4 GHz, 5 GHz bands and broadband Internet access for users with laptops or devices equipped with wireless network interface while roaming within the range of fixed access points (AP) or a public hotspot. Different applications like home entertainment with wireless high-quality multimedia signal transmission, home networking notebooks, mass data storages and printers implement 5–6 GHz Wi-Fi® into their system to offer high-speed wireless connectivity.

When wider coverage areas are needed and especially when a higher order modulation scheme is used such as in emerging very high throughput wireless specifications like 256 Quadrature Amplitude Modulation (QAM) in IEEE 802.11ac, the Signal-to-Noise Ratio (SNR) requirements for both the AP and the client are more stringent. For this kind of high-speed high data rate wireless communication standards, it is essential to ensure the quality of the link path. Major performance criteria of these equipments have to be fulfilled: sensitivity, strong signal capability and interference immunity. Below a general application diagram of a WLAN system is shown.

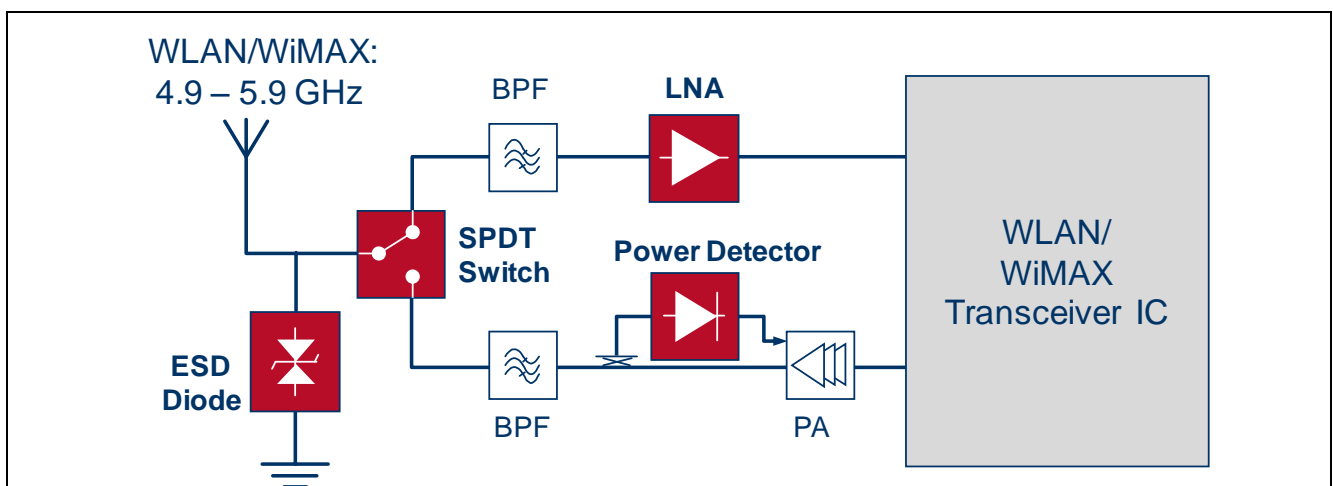


Figure 1 5 – 6 GHz Wi-Fi® Wireless LAN (WLAN, IEEE802.11a/n) and WiMAX (IEEE802.16e) Front-End

In order to increase the system sensitivity, an excellent Low Noise Amplifier (LNA) in front of the receiver is mandatory, especially in an environment with very weak signal strength and because of the insertion loss of the Single Pole, Double Throw (SPDT) switch and the Bandpass Filter (BPF) or diplexer. The typical allowed receiver chain Noise Figure (NF) of approx. 2 dB can only be achieved by using a high-gain low noise amplifier.

In addition, strong signal environment can exist when the equipment is next to a transmitter. In that case, the LNA must be linear enough, i.e. have high 1dB compression point. This avoids saturation, degradation of the gain and increased noise figure.

This application note is focusing on the LNA block, but Infineon does also support with [RF-switches](#), [TVS-diodes](#) for ESD protection and [RF Schottky diodes](#) for power detection.

2 BFP840ESD Overview

2.1 Features

- Robust very low noise amplifier based on Infineon's reliable, high volume SiGe:C technology
- Unique combination of high end RF performance and robustness: 20 dBm maximum RF input power, 1.5 kV HBM ESD hardness
- Very high transition frequency $f_T = 80$ GHz enables very low noise figure at high frequencies: $NF_{min} = 0.85$ dB at 5.5 GHz, 1.8 V, 6 mA
- High gain $|S_{21}|^2 = 18.5$ dB at 5.5 GHz, 1.8 V, 10 mA
- $OIP3 = 23$ dBm at 5.5 GHz, 1.5 V, 6 mA
- Ideal for low voltage applications e.g. $V_{CC} = 1.2$ V and 1.8 V (2.85 V, 3.3 V, 3.6 V requires corresponding collector resistor)
- Low power consumption, ideal for mobile applications
- Easy to use Pb free (RoHS compliant) and halogen free industry standard package with visible leads

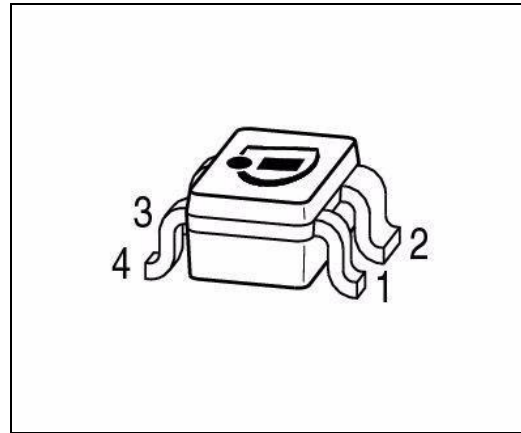


Figure 2 BFP840ESD in SOT343



2.2 Key Applications of BFP840ESD

As Low Noise Amplifier (LNA) in

- Mobile and fixed connectivity applications: WLAN 802.11, WiMAX and UWB
- Satellite communication systems: satellite radio (SDARs, DAB), navigation systems (e.g. GPS, GLONASS) and C-band LNB (1st and 2nd stage LNA)
- Ku-band LNB front-end (2nd stage or 3rd stage LNA and active mixer)
- Ka-band oscillators (DROs)

3 Low Noise Amplifier for 5 to 6 GHz WLAN with BFP840ESD

3.1 Description

BFP840ESD is a discrete hetero-junction bipolar transistor (HBT) specifically designed for high performance 5 GHz band low noise amplifier (LNA) solutions for Wi-Fi connectivity applications. It combines the 80 GHz f_T silicon-germanium:carbide (SiGe:C) B9HFM process with special device geometry technique to reduce the parasitic capacitance between substrate and transistor that degrades high-frequency characteristics, resulting in an inherent input matching and a major improvement in power gain in 5 GHz band together with a low noise figure performance.

The BFP840ESD has an integrated 1.5 kV HBM ESD protection which makes the device robust against electrostatic discharge and extreme RF input power. The device offers its high performance at low current and voltage and is especially well-suited for portable battery powered applications in which low energy consumption is a key requirement.

The BFP840ESD is housed in the industry standard SOT343 package with visible leads. Further variants are available in flat-lead TSFP-4-1 package (BFP840FESD) and in the low-height 0.31mm TSLP-3-9 package (BFR840L3RHESD) specially fitting into modules.

Figure 3 shows the pin assignment of package of BFP840ESD in the top view:

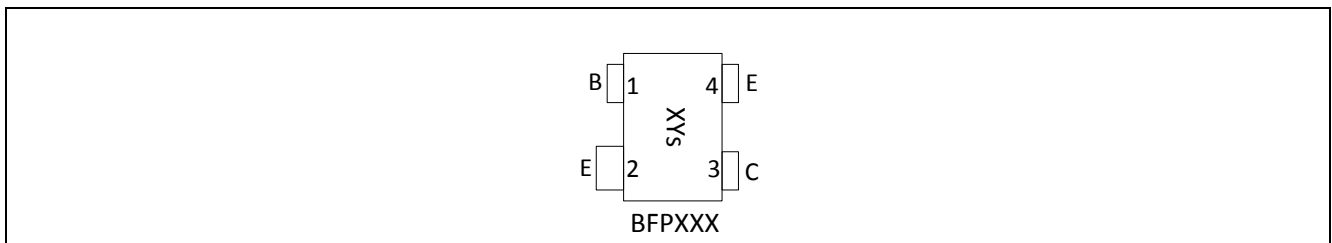


Figure 3 Package and pin connections of BFP840ESD in Topview

This application note presents the measurement results of the LNA using BFP840ESD for 5100 MHz to 5900 MHz WLAN applications, with 2.4 GHz notch filter. Proper RF grounding on PCB has to be ensured in order to achieve stability k -factor ≥ 1 above 8.5 GHz (Figure 21).

The application circuit requires 12 passive 0402 Surface Mounted Device (SMD) components and achieves the gain from 16.2 dB to 15.6 dB over the frequency band. The NF varies from 1.1 dB to 1.22 dB (SMA and PCB losses are subtracted) over the frequency band. The circuit achieves an input and output return loss better than 12.2 dB. Furthermore, the circuit is unconditionally stable from 10 MHz to 15 GHz. At 5.5 GHz, -9.3 dBm input compression point (IP1dB) is achieved, together with the 16.8 dBm output third intercept point (OIP3) measured with 1MHz tone spacing. In the off mode this circuit has 1dB input compression point more than 10 dBm for the whole frequency band.

The BFP840ESD could help you build a high-performance cost-effective solution for your upcoming 5GHz WLAN IEEE802.11a/n/ac designs.

3.2 Performance Overview

Device: BFP840ESD

Application: Low Noise Amplifier for 5 to 6 GHz WLAN Application

PCB Marking: M130121 BFP840ESD SOT343 (0.4mm x 2)

Table 1 Summary of Measurement Results

Parameter	Symbol	Value				Unit	Note/Test Condition
DC Voltage	V_{CC}	3.0				V	
DC Current	I_{CC}	11.2				mA	
Frequency Range	Freq	2400	5100	5500	5900	MHz	
ON-Mode Gain	G_{ON}	-9	16.2	16.3	15.6	dB	
OFF-Mode Gain	G_{OFF}	-	-25	-26.2	-27.5	dB	$V_{CC} = 0\text{ V}$, $I_{CC} = 0\text{ mA}$
Noise Figure	NF	-	1.1	1.17	1.22	dB	SMA and PCB losses (~0.12 dB) are subtracted
Input Return Loss	RL_{in}	-	12.2	15.4	20.3	dB	
Output Return Loss	RL_{out}	-	20.3	17	13	dB	
Reverse Isolation	IR_{ev}	-	25.7	24.9	24.3	dB	
ON-Mode Input P1dB	$IP1dB_{ON}$	5	-9.5	-9.3	-9.2	dBm	
OFF-Mode Input P1dB	$IP1dB_{OFF}$	-	>10	>10	>10	dBm	$V_{CC} = 0\text{ V}$, $I_{CC} = 0\text{ mA}$
Output P1dB	$OP1dB$	-5	5.7	6	5.4	dBm	
Input IP3	$IIP3$	0.5				dBm	
Output IP3	$OIP3$	16.8				dBm	Power @ Input: -30 dBm $f_1 = 5500\text{ MHz}$, $f_2 = 5501\text{ MHz}$
Stability	k	>1				--	Stability measured from 10 MHz to 15 GHz

3.3 Schematics and Bill-of-Materials

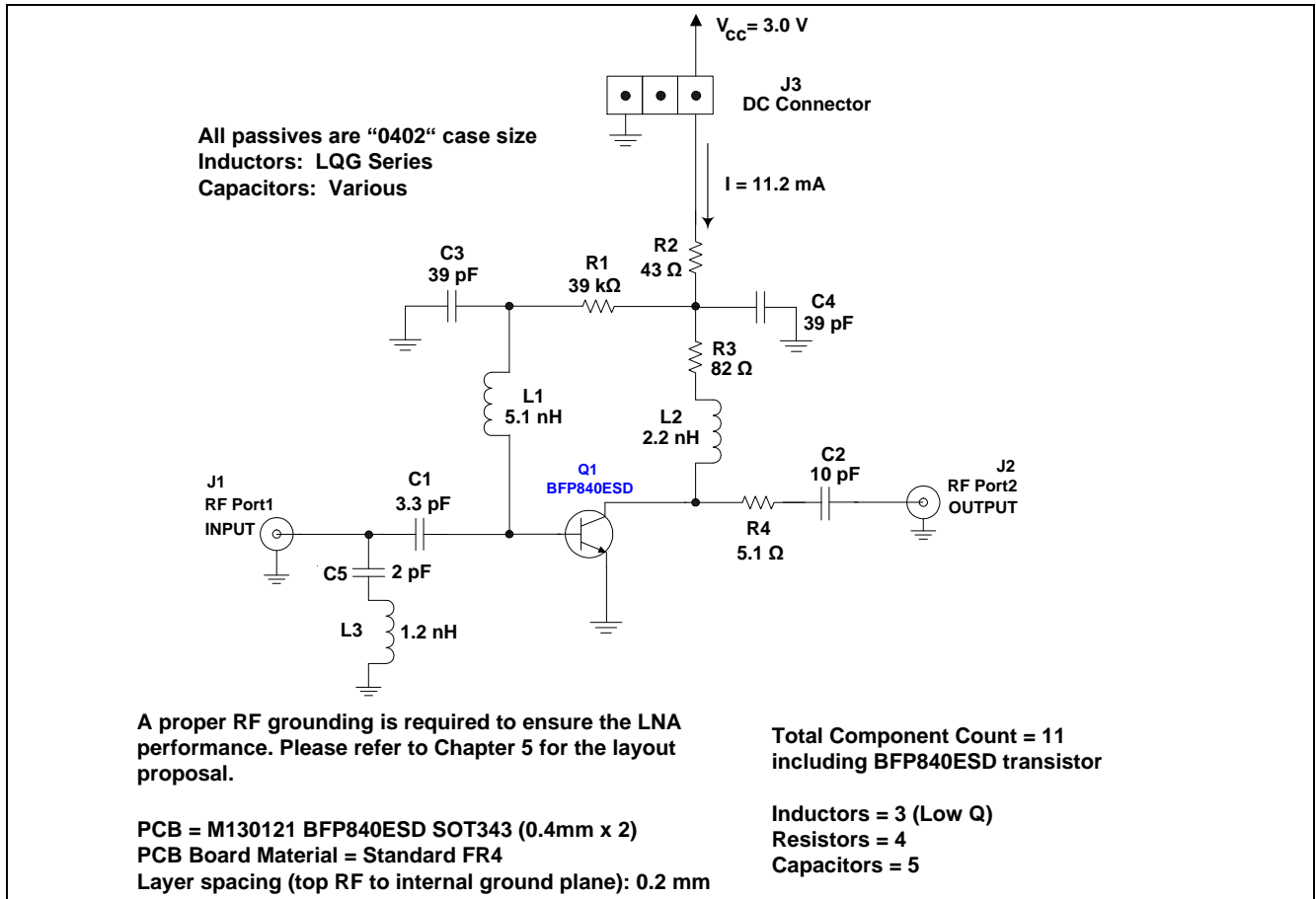


Figure 4 Schematic Diagram of the used Circuit

Table 2 Bill-of-Materials

Symbol	Value	Unit	Size	Manufacturer	Comment
C1	3.3	pF	0402	Various	Input DC block, Noise & input matching
C2	10	pF	0402	Various	Output DC block & output matching
C3, C4	39	pF	0402	Various	RF decoupling / blocking cap
C5	2	pF	0402	Various	Input matching & 2.4 GHz rejection
L1	5.1	nH	0402	Murata LQG series	Noise & input matching
L2	2.2	nH	0402	Murata LQG series	Output matching & high frequency stability improvement
L3	1.2	nH	0402	Murata LQG series	Input matching & 2.4 GHz rejection
R1	39	kΩ	0402	Various	DC biasing
R2	43	Ω	0402	Various	DC biasing (provides DC negative feedback to stabilize DC operating point over temperature variation, transistor h_{FE} variation, etc.)
R3	82	Ω	0402	Various	Stability improvement & output matching
R4	5.1	Ω	0402	Various	High frequency stability improvement
Q1			SOT343	Infineon Technologies	BFP840ESD SiGe:C HBT

4 Measured Graphs

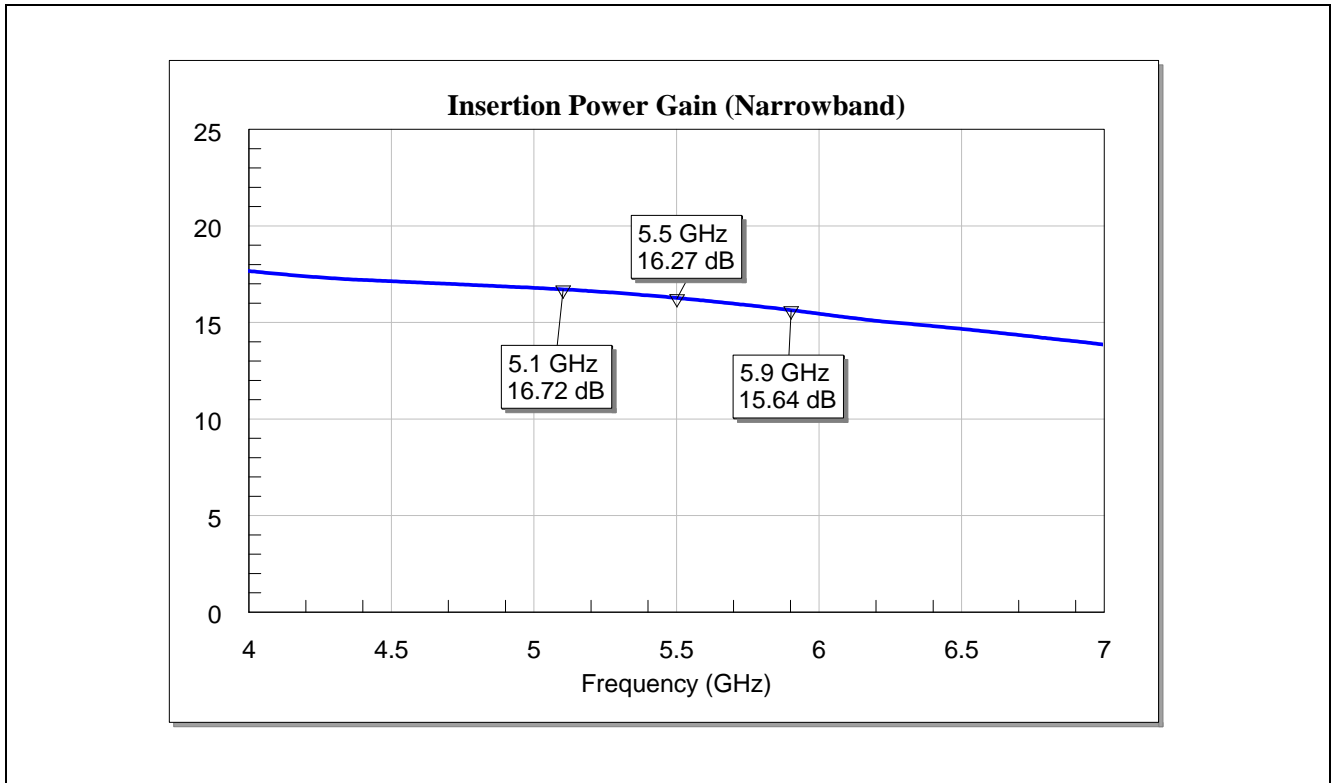


Figure 5 Insertion Power Gain of the 5-6 GHz WLAN LNA with BFP840ESD

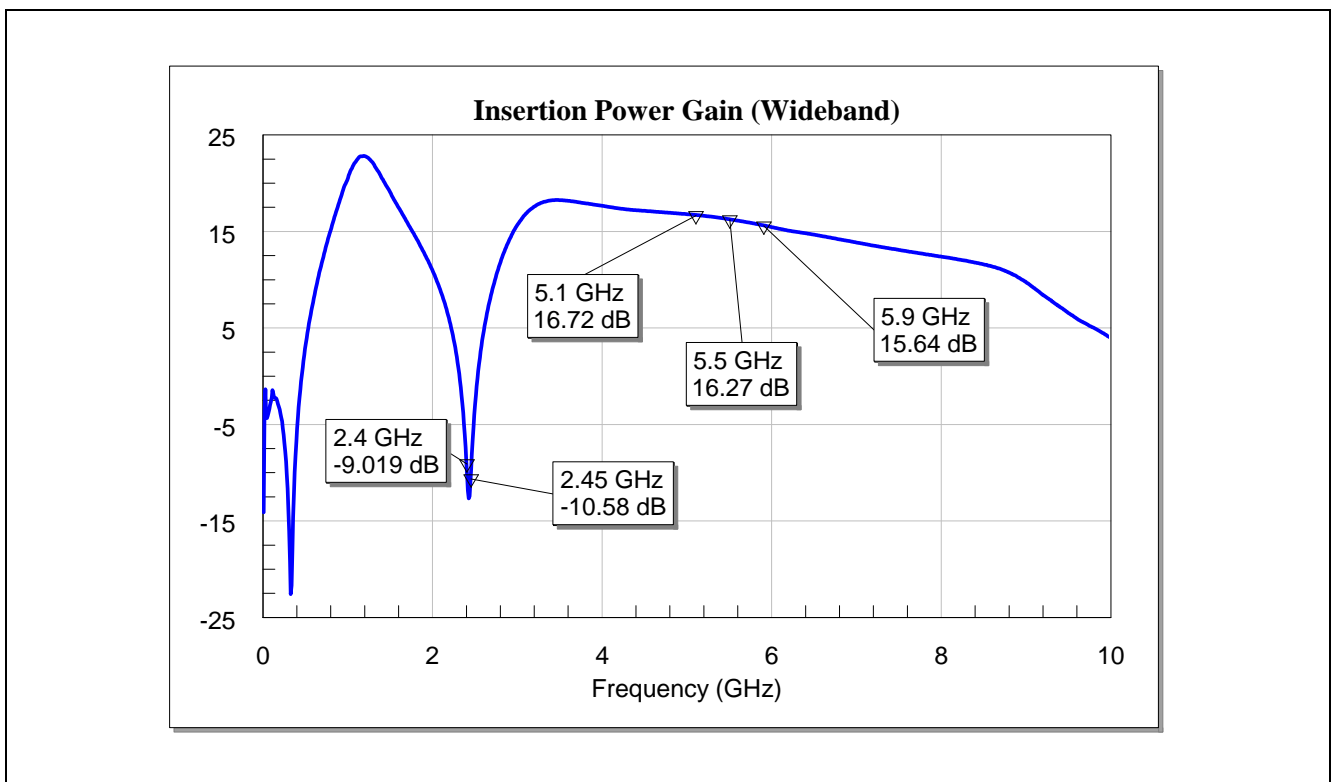


Figure 6 Wideband Insertion Power Gain of the 5-6 GHz WLAN LNA with BFP840ESD

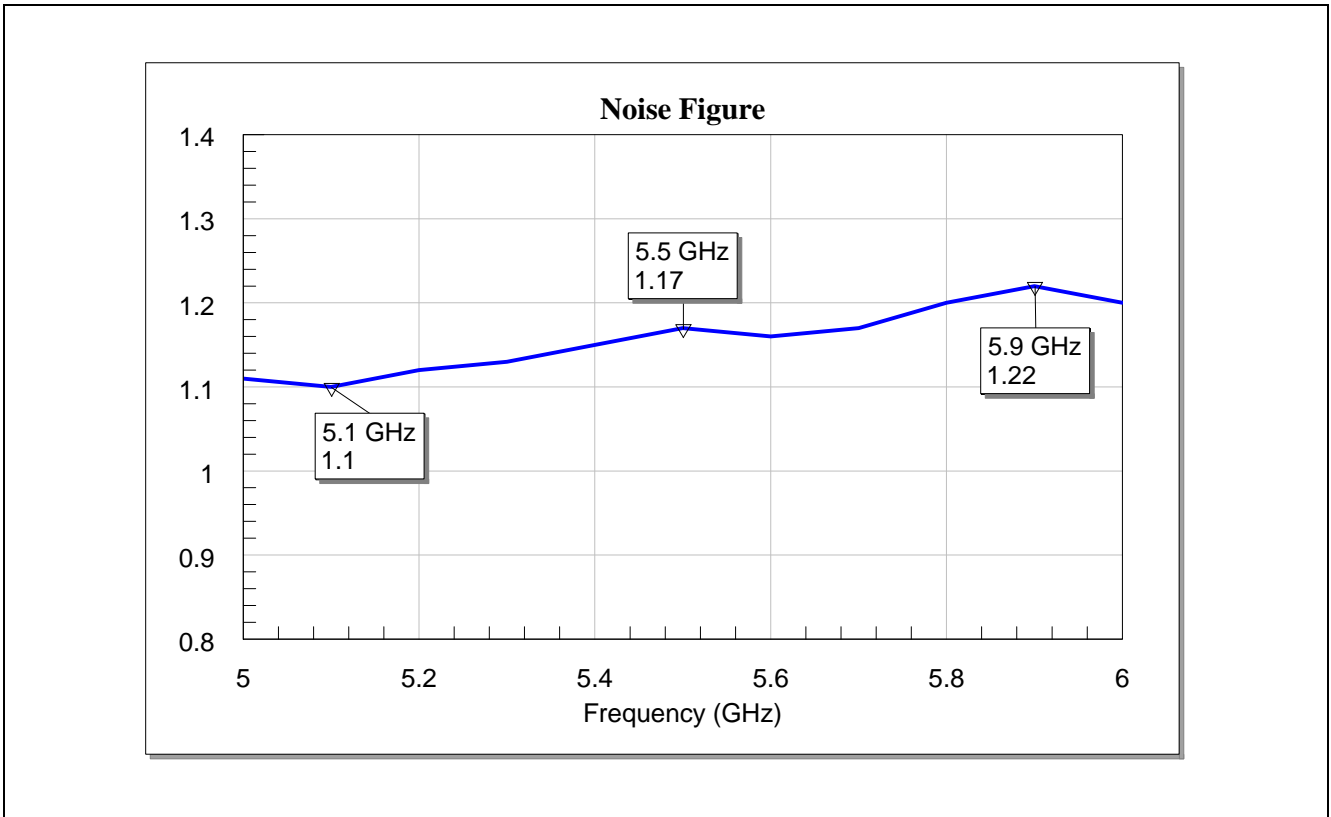


Figure 7 Noise Figure of BFP840ESD LNA for 5100 - 5900 MHz

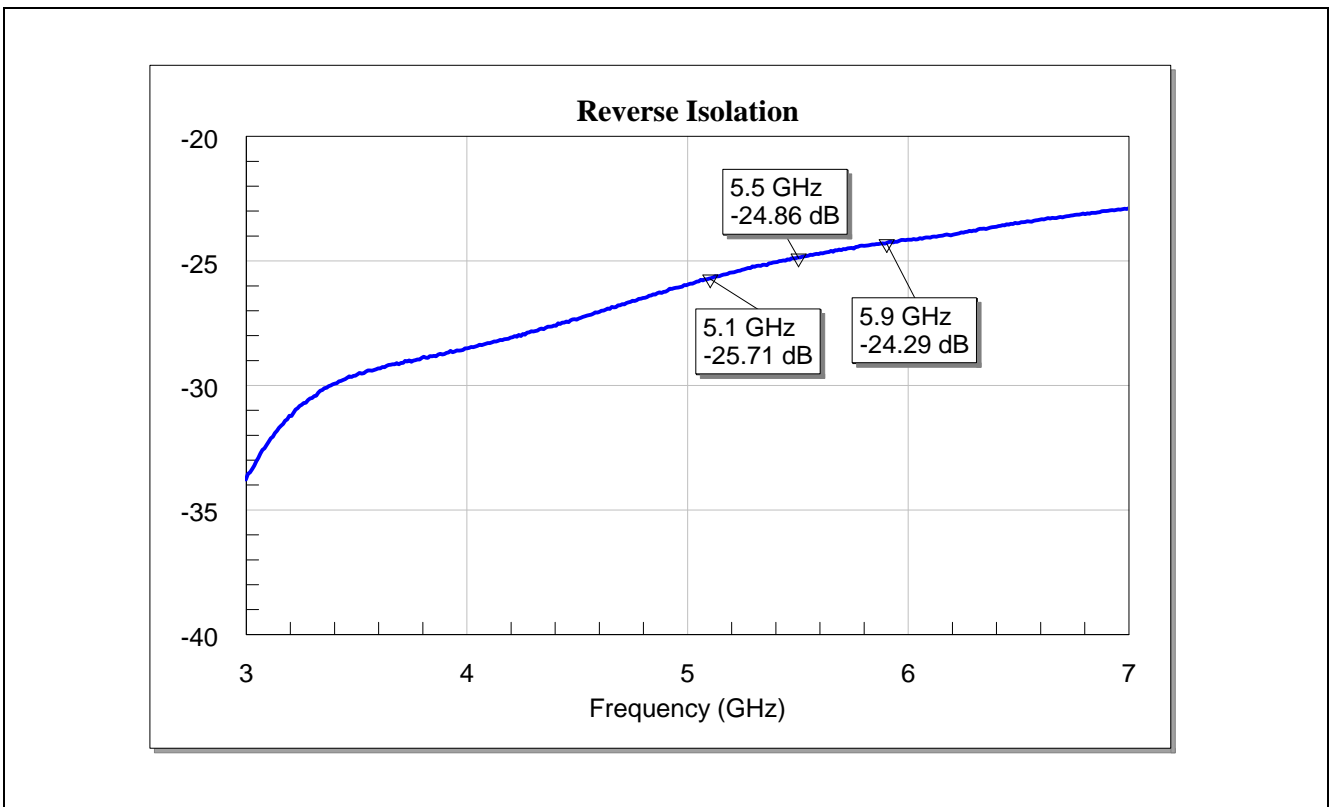


Figure 8 Reverse Isolation of the 5-6 GHz WLAN LNA with BFP840ESD

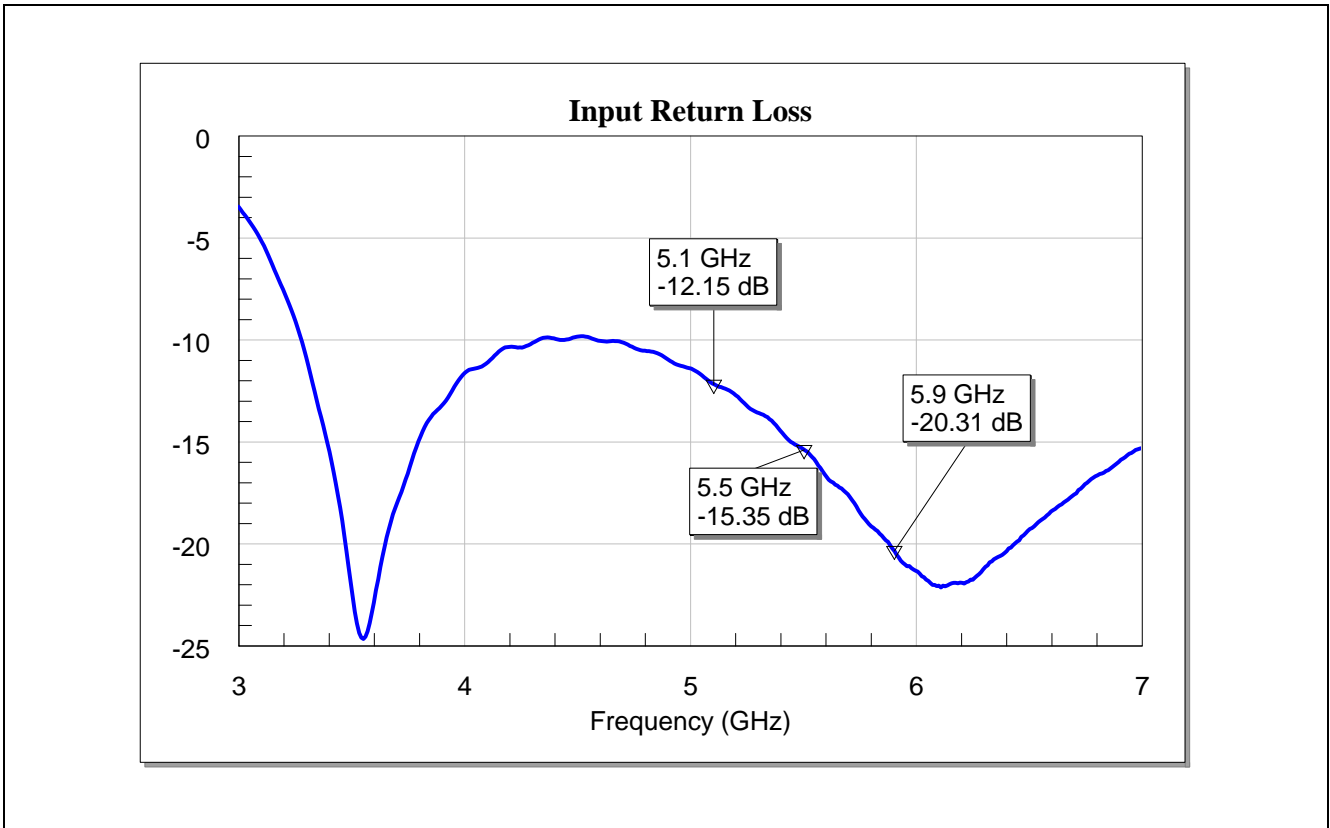


Figure 9 Input Matching of the 5-6 GHz WLAN LNA with BFP840ESD

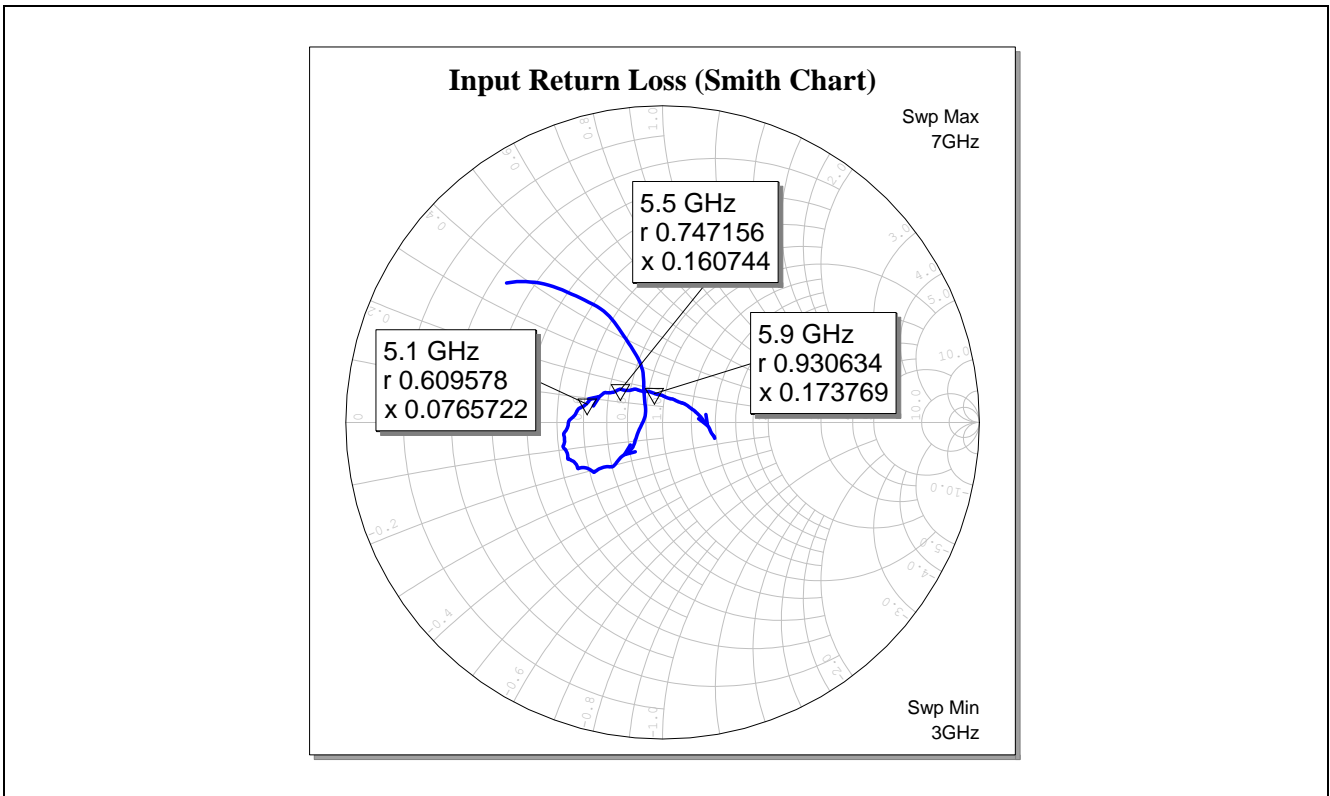


Figure 10 Input Matching of the 5-6 GHz WLAN LNA with BFP840ESD (Smith Chart)

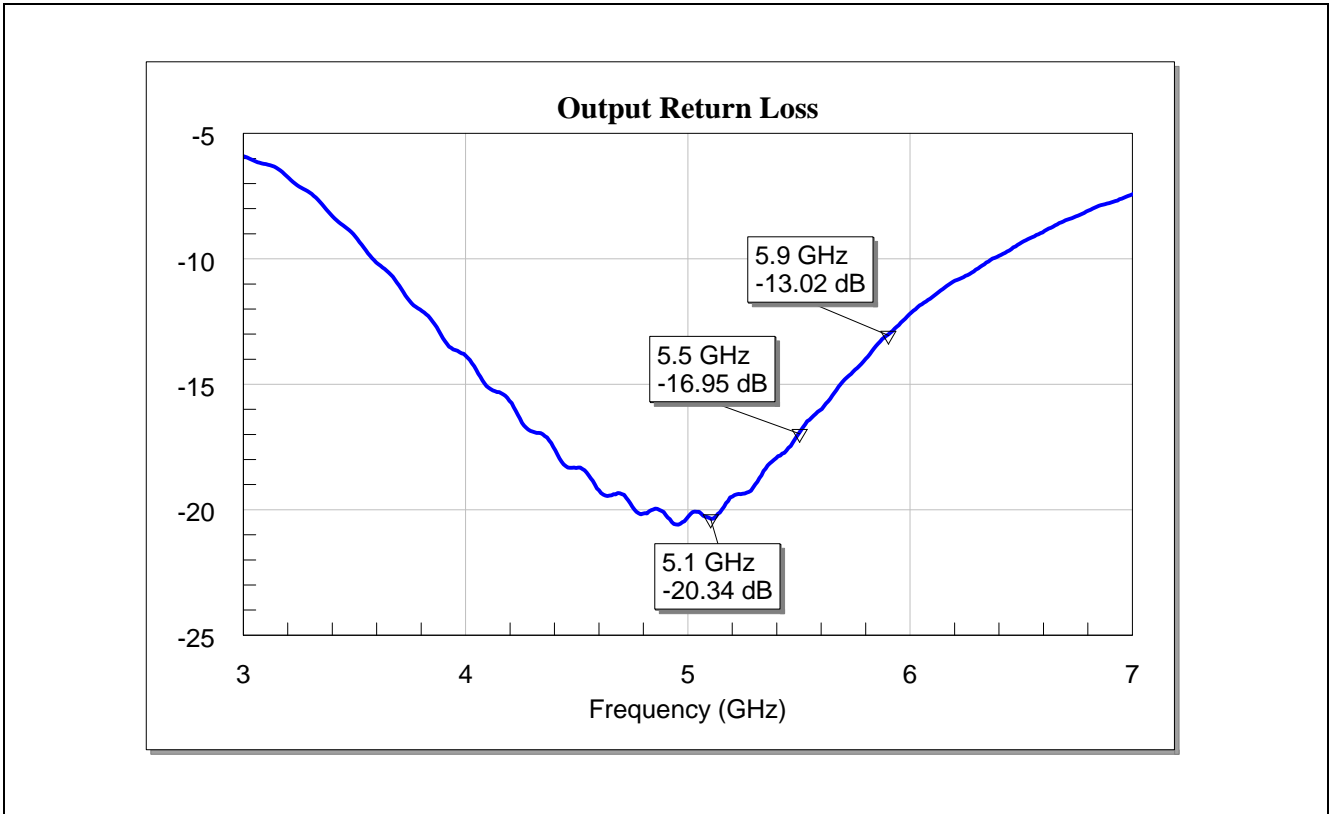


Figure 11 Output Matching of the 5-6 GHz WLAN LNA with BFP840ESD

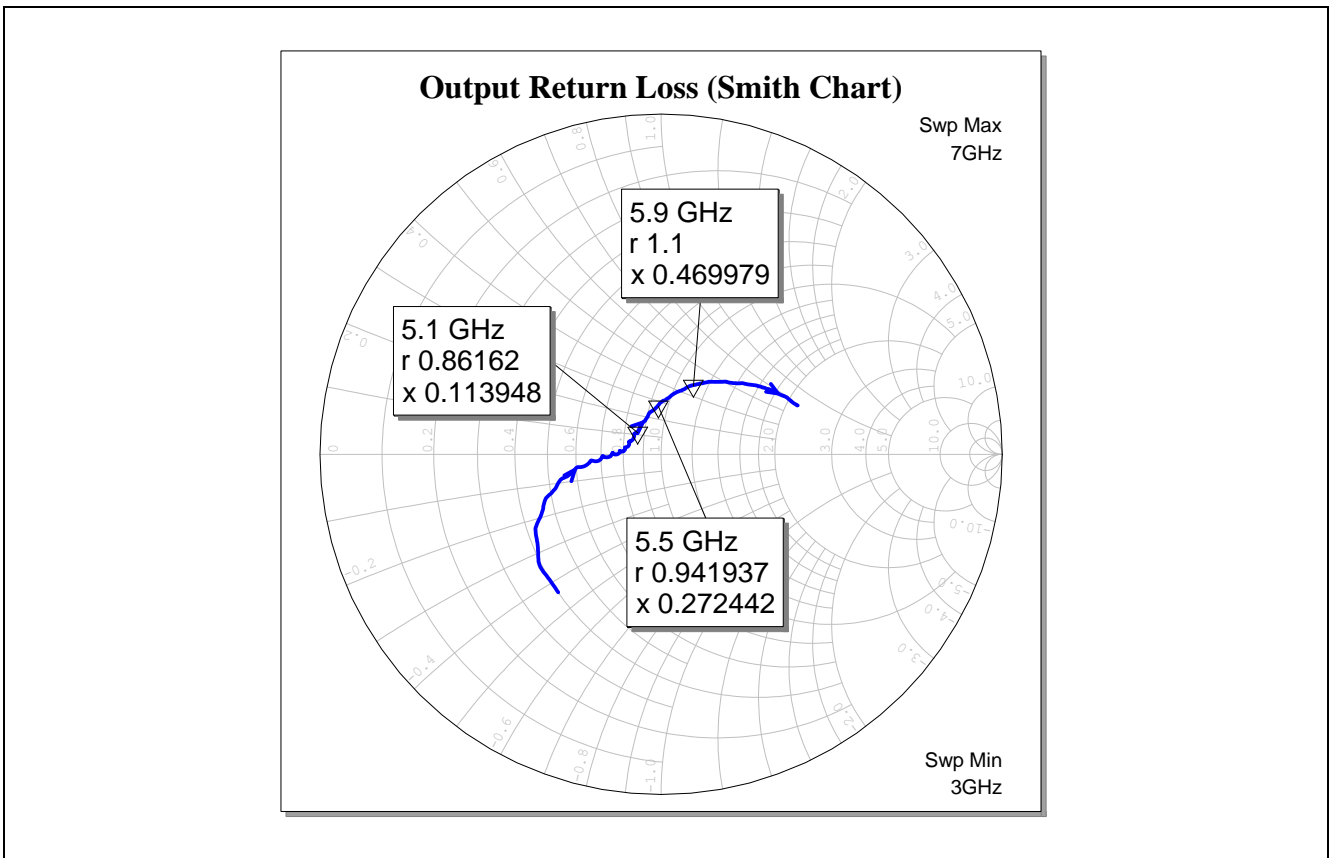


Figure 12 Output Matching of the 5-6 GHz WLAN LNA with BFP840ESD (Smith Chart)

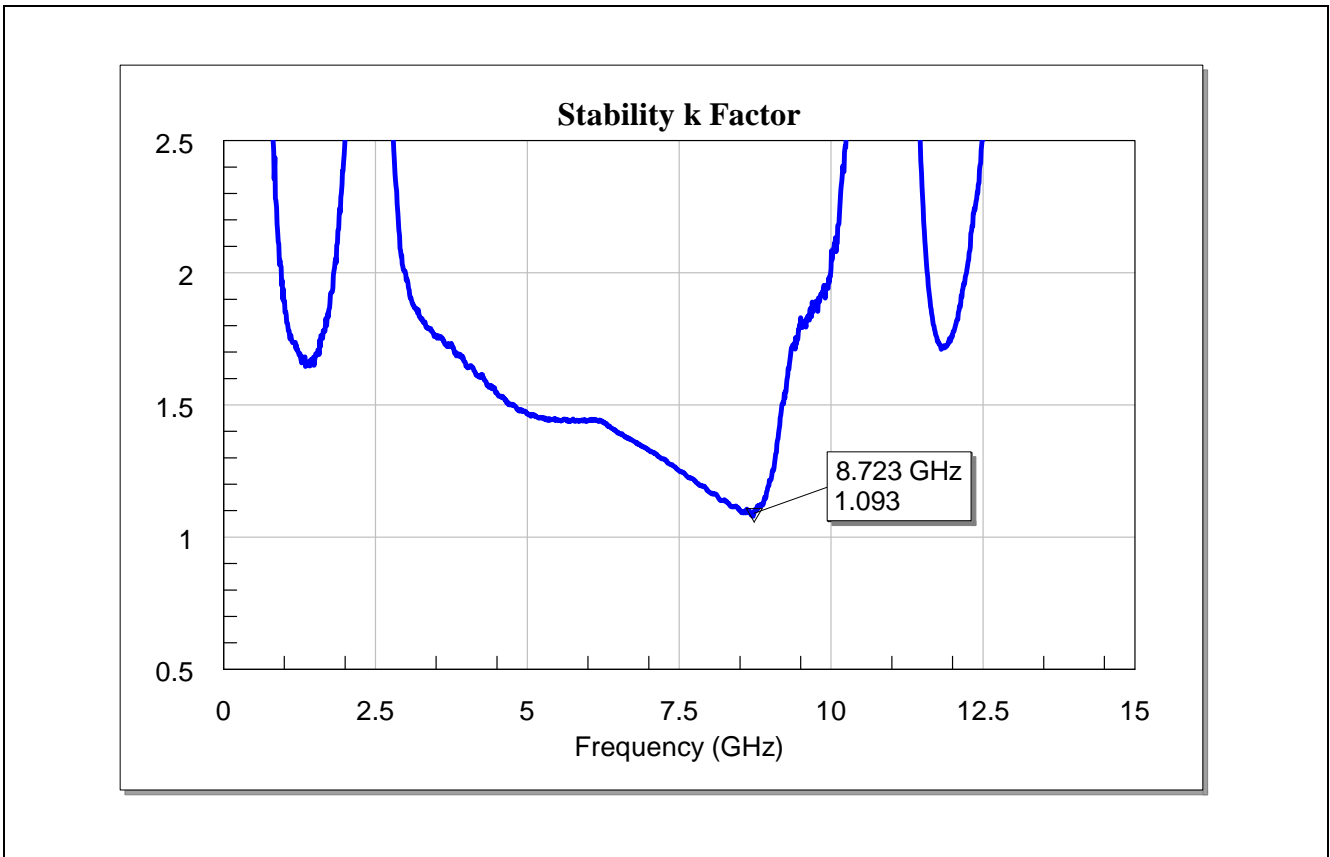


Figure 13 Wideband Stability k Factor of the 5-6 GHz WLAN LNA with BFP840ESD

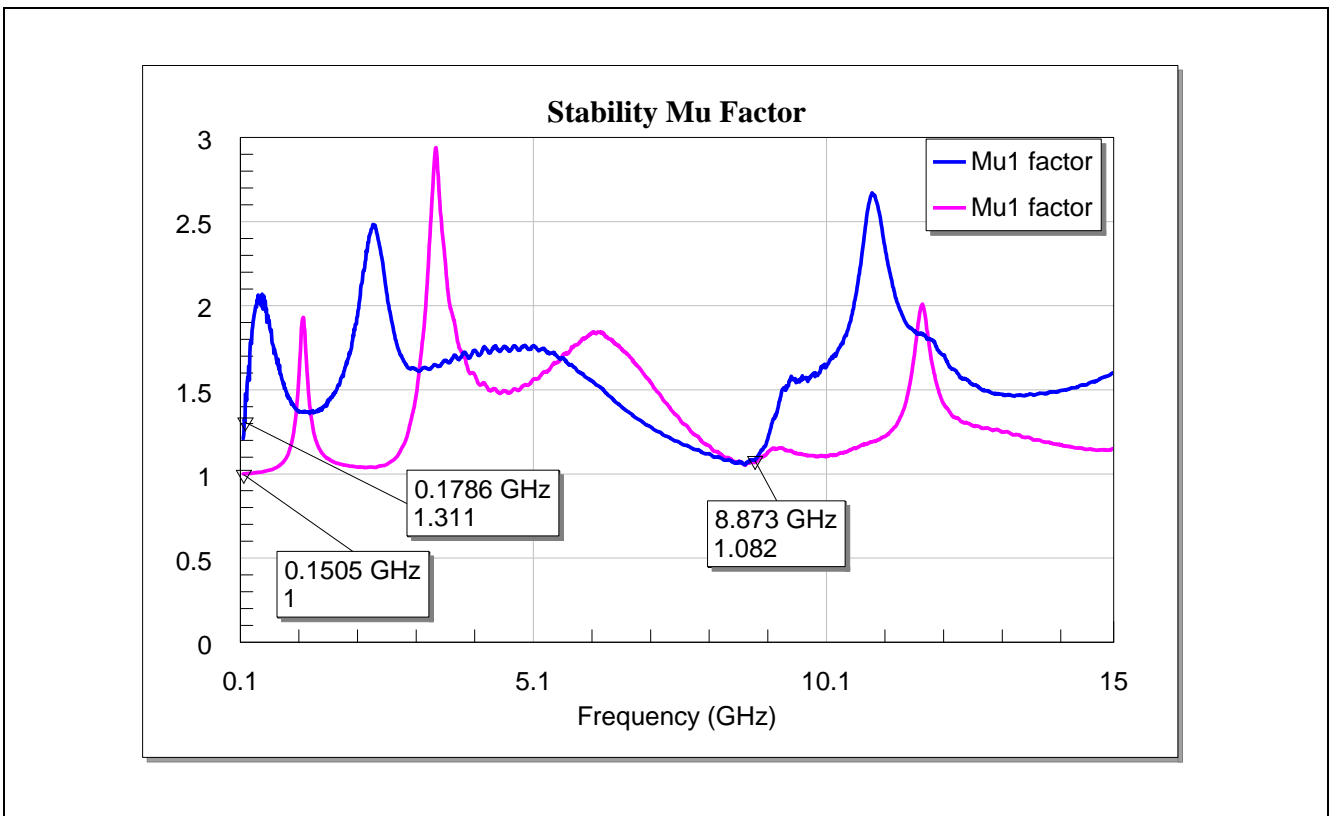


Figure 14 Wideband Stability Mu Factor of the 5-6 GHz WLAN LNA with BFP840ESD

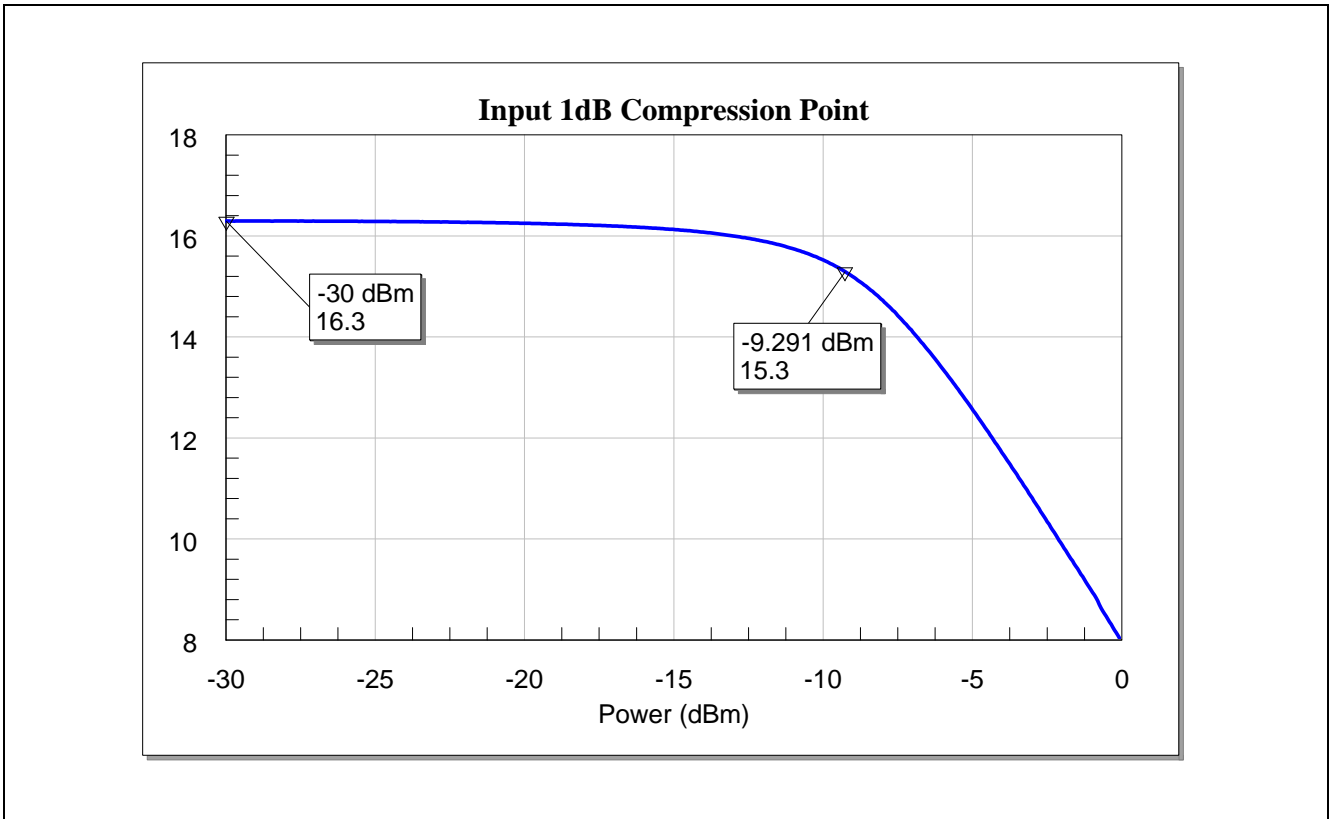


Figure 15 Input 1dB Compression Point of the LNA with BFP840ESD at 5500 MHz

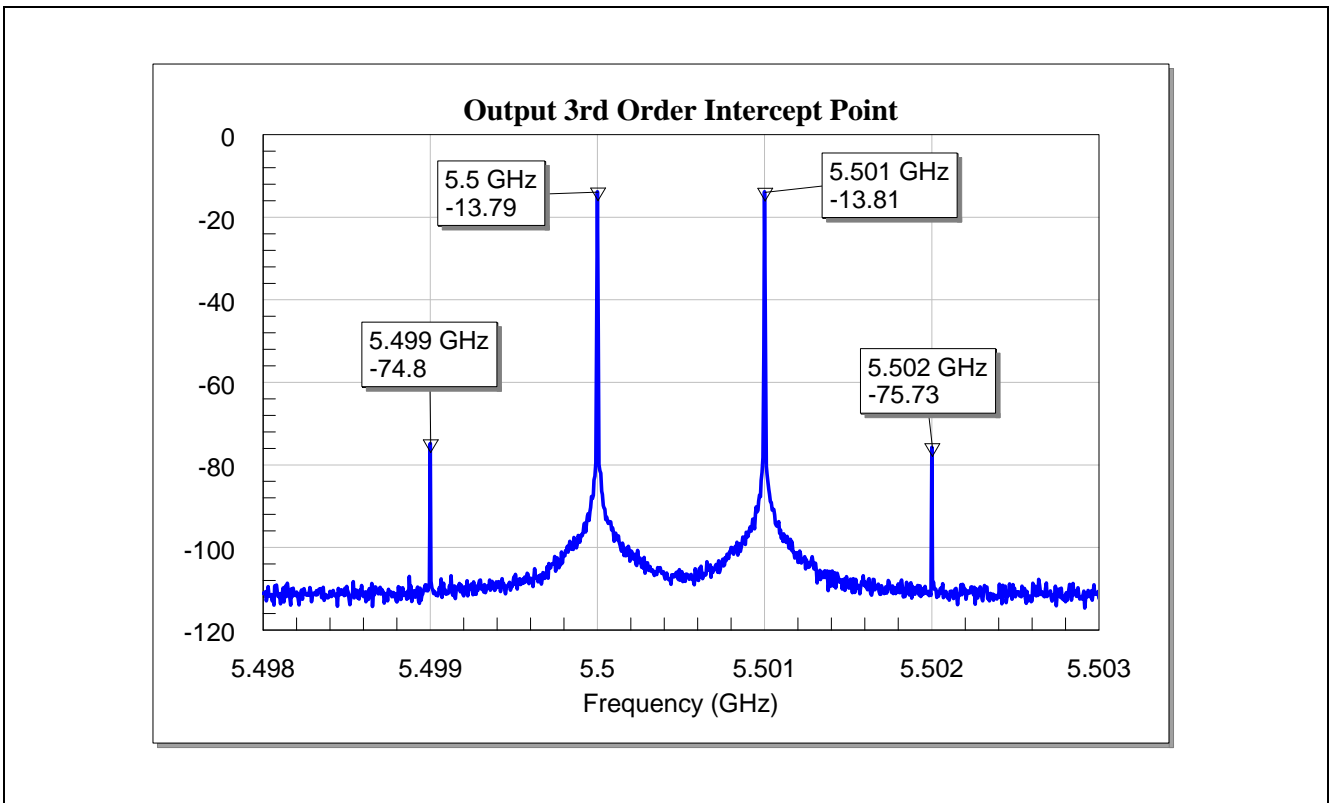


Figure 16 Output 3rd Order Intercept Point of LNA with BFP840ESD at 5500 MHz (LNA input power = -30 dBm)

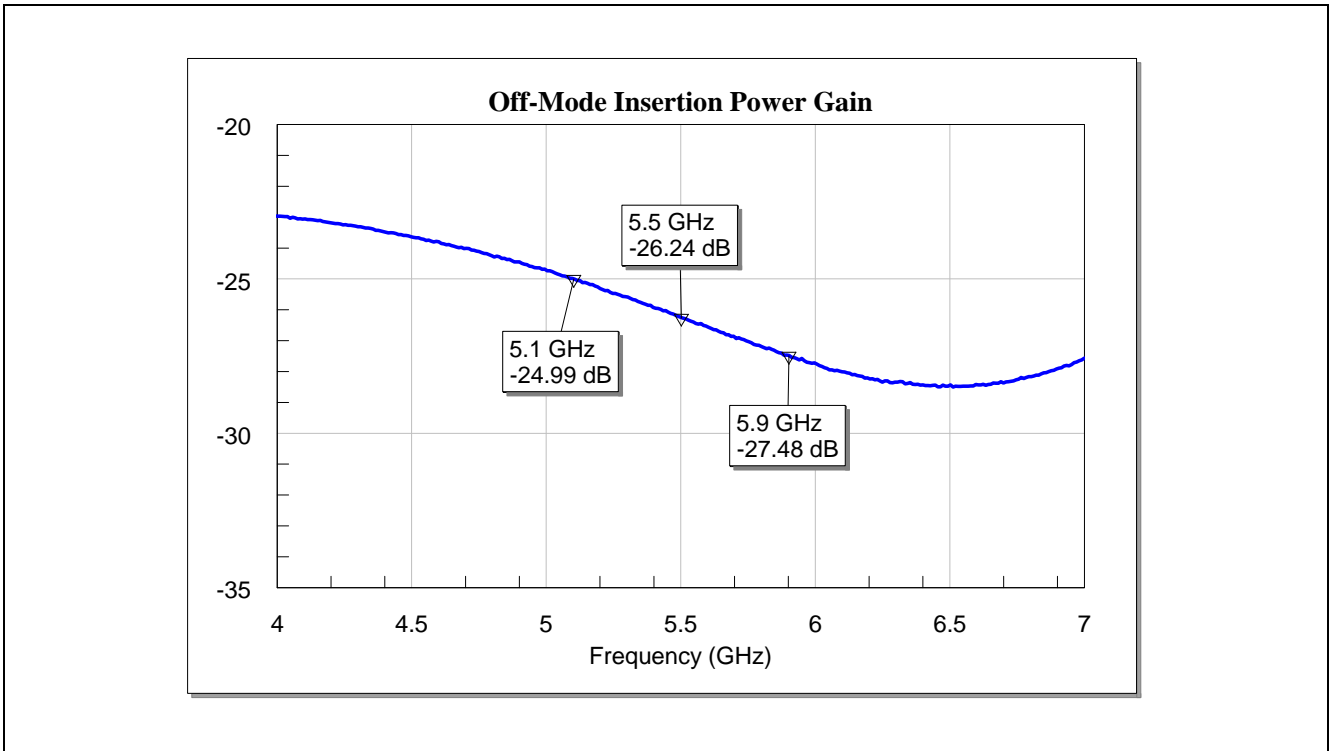


Figure 17 OFF-Mode ($V_{cc} = 0V$, $I_{cc} = 0mA$) Insertion Power Gain of the 5-6 GHz WLAN LNA with BFP840ESD

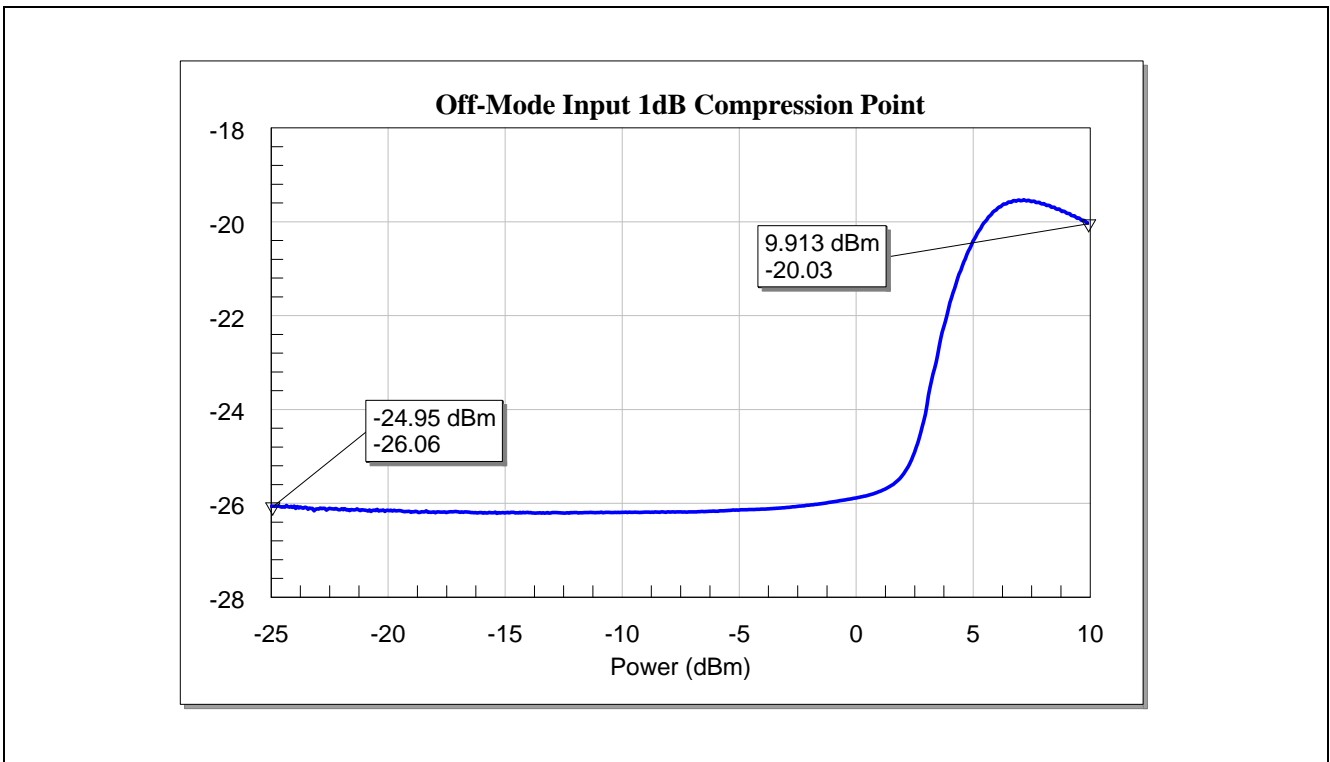


Figure 18 OFF-Mode Input 1dB Compression of the 5-6 GHz WLAN LNA with BFP840ESD at 5500 MHz

5 Evaluation Board and Layout Information

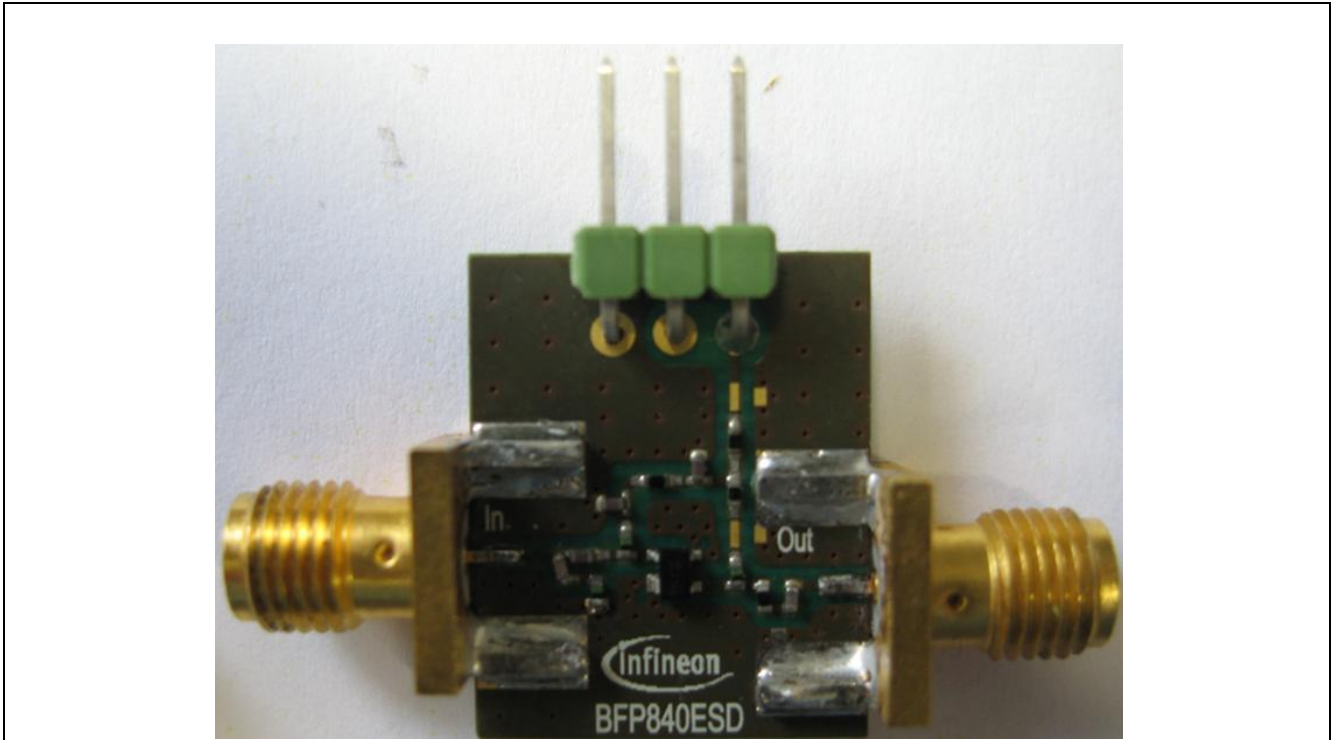


Figure 19 Photo of the BFP840ESD 5-6 GHz WLAN LNA Evaluation Board

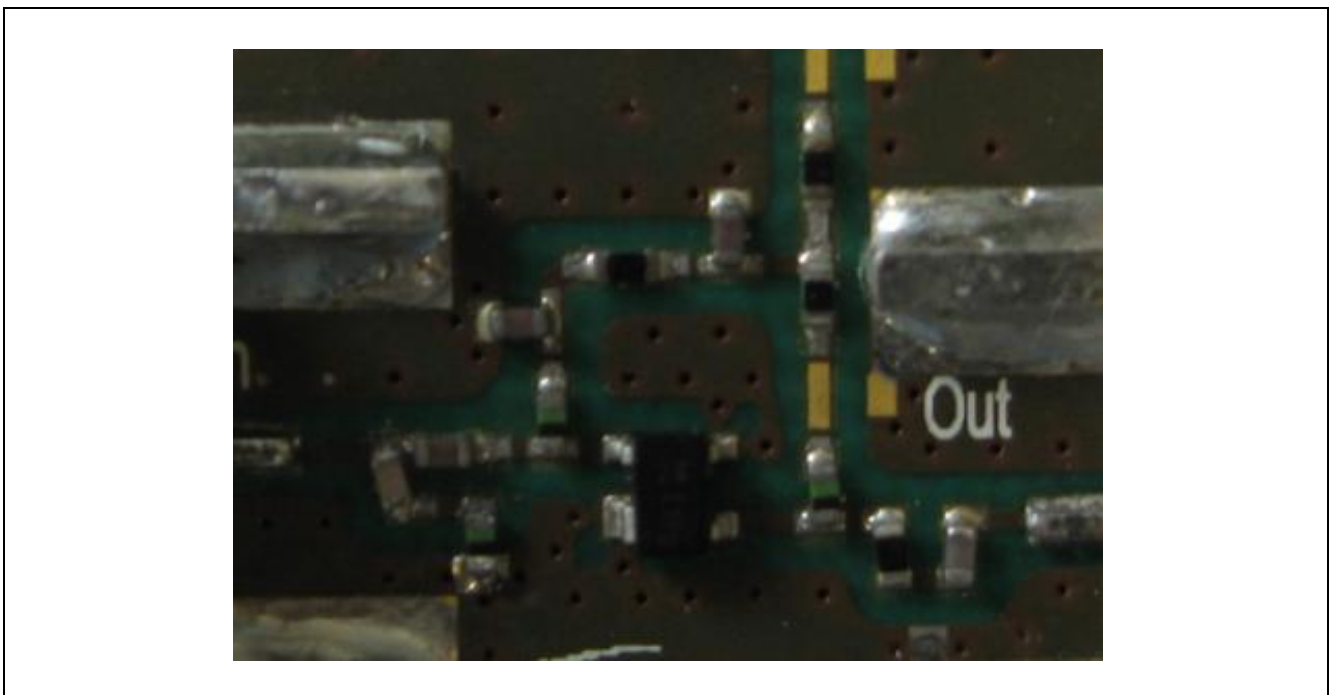


Figure 20 Zoom-In Picture of the BFP840ESD 5-6 GHz WLAN LNA Evaluation Board

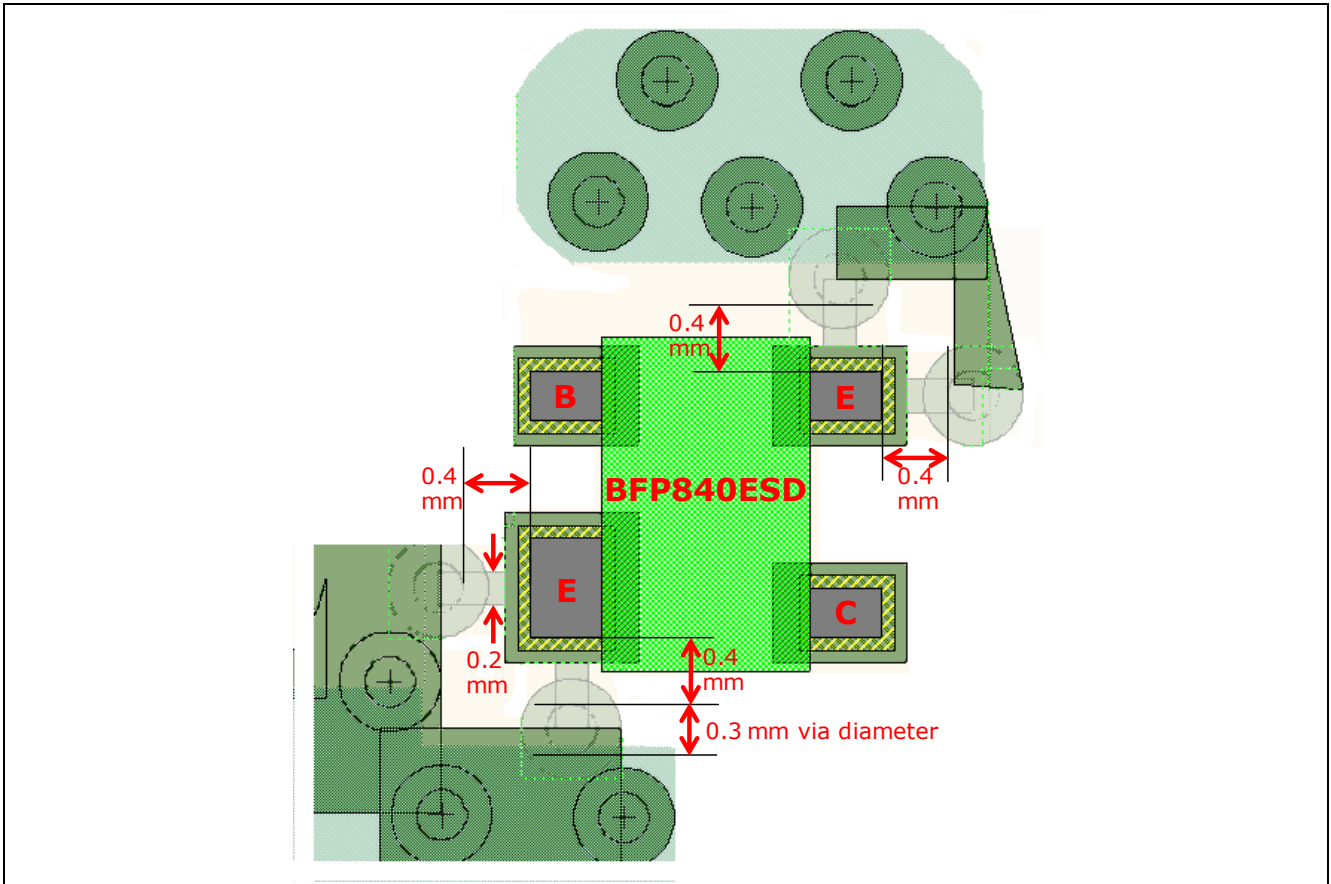


Figure 21 Layout Proposal for RF Grounding of the 5-6 GHz WLAN LNA with BFP840ESD

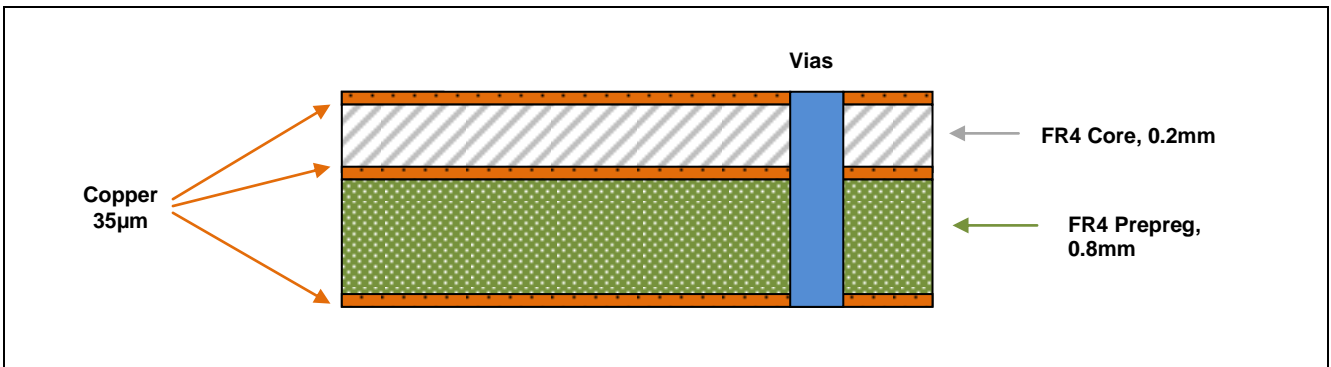


Figure 22 PCB Layer Information

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7 Remark

The graphs are generated with the simulation program AWR Microwave Office®.

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